

Features

- Single USB port power switches
- Over-current and thermal protection
- 1.5A accurate current limiting
- Reverse Current Blocking
- 95mΩ on-resistance
- Input voltage range: 2.7V – 5.5V
- 0.6ms typical rise time
- Very low shutdown current: 1uA (max)
- Fault report (FLG) with blanking time (7ms typ)
- ESD protection: 4KV HBM, 400V MM
- Active low (AP2161) or active high (AP2171) enable
- Ambient temperature range -40°C to 85°C
- SOT25, SOP-8L, MSOP-8L-EP (Exposed Pad), and DFN2018-6: Available in “Green” Molding Compound (No Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)
- UL Recognized, File Number E322375
- IEC60950-1 CB Scheme Certified

Description

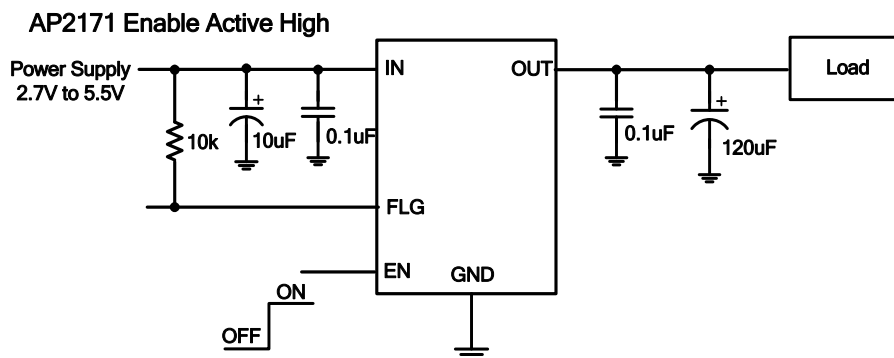
The AP2161 and AP2171 are integrated high-side power switches optimized for Universal Serial Bus (USB) and other hot-swap applications. The family of devices complies with USB 2.0 and available with both polarities of Enable input. They offer current and thermal limiting and short circuit protection as well as controlled rise time and under-voltage lockout functionality. A 7ms deglitch capability on the open-drain Flag output prevents false over-current reporting and does not require any external components.

All devices are available in SOP-8L, MSOP-8L-EP, SOT25, and DFN2018-6 packages.

Applications

- Consumer electronics – LCD TV & Monitor, Game Machines
- Communications – Set-Top-Box, GPS, Smartphone
- Computing – Laptop, Desktop, Servers, Printers, Docking Station, HUB

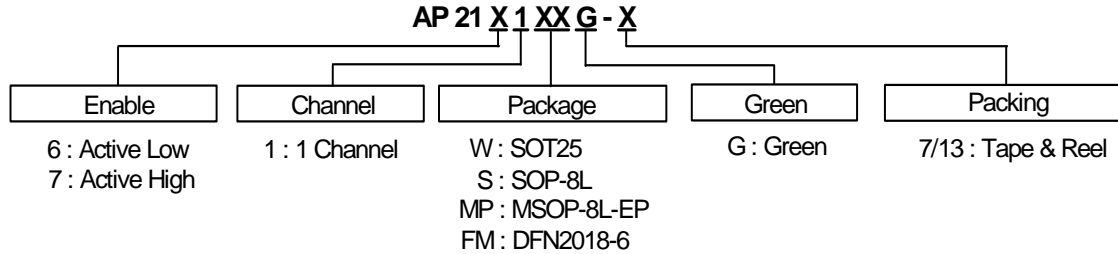
Typical Application Circuit



Available Options

Part Number	Channel	Enable pin (EN)	Current limit (typical)	Recommended maximum continuous load current
AP2161	1	Active Low	1.5A	1.0A
AP2171	1	Active High	1.5A	1.0A

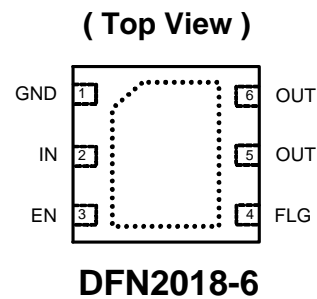
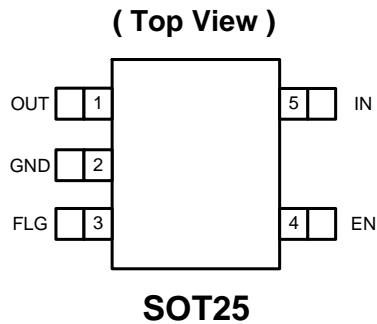
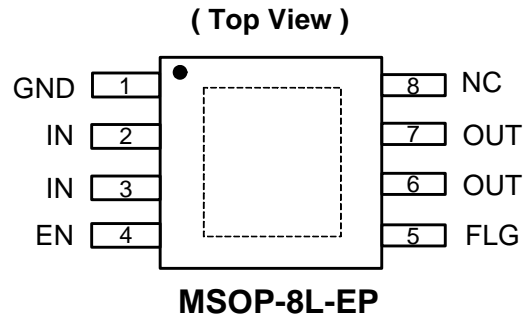
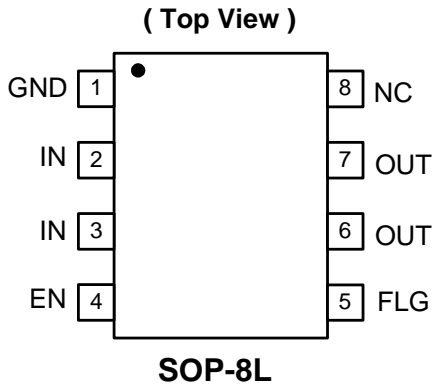
Ordering Information



Device	Package Code	Packaging (Note 2)	7"/13" Tape and Reel	
			Quantity	Part Number Suffix
AP21X1WG-7	W	SOT25	3000/Tape & Reel	-7
AP21X1SG-13	S	SOP-8L	2500/Tape & Reel	-13
AP21X1MPG-13	MP	MSOP-8L-EP	2500/Tape & Reel	-13
AP21X1FMG-7	FM	DFN2018-6	3000/Tape & Reel	-7

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html
 2. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

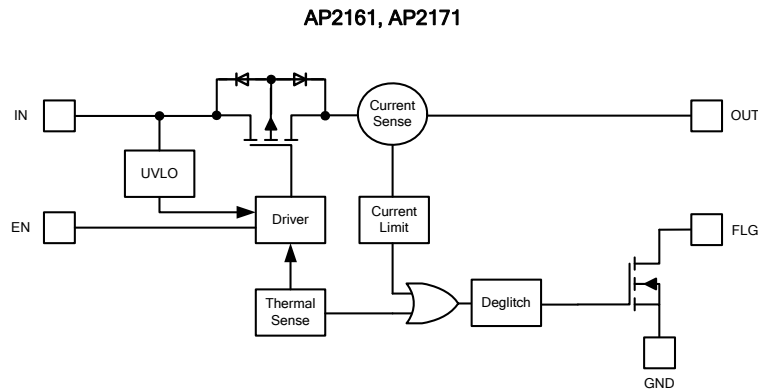
Pin Assignment



Pin Descriptions

Pin Name	Pin Number			Descriptions
	SOP-8L	SOT25	DFN2018-6	
	MSOP-8L-EP			
GND	1	2	1	Ground
IN	2, 3	5	2	Voltage input pin (all IN pins must be tied together externally)
EN	4	4	3	Enable input, active low (AP2161) or active high (AP2171)
FLG	5	3	4	Over-current and over-temperature fault report; open-drain flag is active low when triggered
OUT	6, 7	1	5, 6	Voltage output pin (all OUT pins must be tied together externally)
NC	8	N/A	N/A	No internal connection; recommend tie to OUT pins

Functional Block Diagram



Absolute Maximum Ratings

Symbol	Parameter	Ratings	Units
ESD HBM	Human Body Model ESD Protection	4	KV
ESD MM	Machine Model ESD Protection for MSOP-8L-EP, SOT25 packages	400	V
	Machine Model ESD Protection for DFN2018-6, SOP-8L packages	300	V
V_{IN}	Input Voltage	6.5	V
V_{OUT}	Output Voltage	$V_{IN} + 0.3$	V
V_{EN}, V_{FLG}	Enable Voltage	6.5	V
I_{load}	Maximum Continuous Load Current	Internal Limited	A
T_{Jmax}	Maximum Junction Temperature	150	°C
T_{ST}	Storage Temperature Range (Note 3)	-65 to 150	°C

Notes: 3. UL Recognized Rating from -30°C to 70°C (Diodes qualified T_{ST} from -65°C to 150°C)

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{IN}	Input voltage	2.7	5.5	V
I_{OUT}	Output Current	0	1.0	A
T_A	Operating Ambient Temperature	-40	85	°C

Electrical Characteristics

($T_A = 25^\circ\text{C}$, $V_{IN} = +5.0\text{V}$, unless otherwise stated)

Symbol	Parameter	Test Conditions	Min	Typ.	Max	Unit	
V_{UVLO}	Input UVLO	$R_{load}=1\text{k}\Omega$	1.6	1.9	2.5	V	
I_{SHDN}	Input Shutdown Current	Disabled, $I_{OUT}=0$		0.5	1	μA	
I_Q	Input Quiescent Current	Enabled, $I_{OUT}=0$		45	70	μA	
I_{LEAK}	Input Leakage Current	Disabled, OUT grounded			1	μA	
I_{REV}	Reverse Leakage Current	Disabled, $V_{IN}=0\text{V}$, $V_{OUT}=5\text{V}$, I_{REV} at V_{IN}		1		μA	
$R_{DS(ON)}$	Switch on-resistance	$V_{IN} = 5\text{V}$, $I_{OUT} = 1\text{A}$	$T_A = 25^\circ\text{C}$	SOT25, MSOP-8L-EP, SOP-8L	95	115	m Ω
			$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	DFN2018-6	90	110	
		$V_{IN} = 3.3\text{V}$, $I_{OUT} = 1\text{A}$	$T_A = 25^\circ\text{C}$		120	140	
			$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$			170	
I_{SHORT}	Short-Circuit Current Limit	Enabled into short circuit, $C_L=68\mu\text{F}$		1.2		A	
I_{LIMIT}	Over-Load Current Limit	$V_{IN}=5\text{V}$, $V_{OUT}=4.6\text{V}$, $C_L=68\mu\text{F}$, $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	1.1	1.5	1.9	A	
I_{Trig}	Current limiting trigger threshold	Output Current Slew rate ($<100\text{A/s}$), $C_L=68\mu\text{F}$		2.0		A	
V_{IL}	EN Input Logic Low Voltage	$V_{IN} = 2.7\text{V}$ to 5.5V			0.8	V	
V_{IH}	EN Input Logic High Voltage	$V_{IN} = 2.7\text{V}$ to 5.5V	2			V	
I_{SINK}	EN Input leakage	$V_{EN} = 5\text{V}$			1	μA	
$T_{D(ON)}$	Output turn-on delay time	$C_L=1\mu\text{F}$, $R_{load}=10\Omega$		0.05		ms	
T_R	Output turn-on rise time	$C_L=1\mu\text{F}$, $R_{load}=10\Omega$		0.6	1.5	ms	
$T_{D(OFF)}$	Output turn-off delay time	$C_L=1\mu\text{F}$, $R_{load}=10\Omega$		0.01		ms	
T_F	Output turn-off fall time	$C_L=1\mu\text{F}$, $R_{load}=10\Omega$		0.05	0.1	ms	
R_{FLG}	FLG output FET on-resistance	$I_{FLG} = 10\text{mA}$		20	40	Ω	
T_{Blank}	FLG blanking time	$C_{IN}=10\mu\text{F}$, $C_L=68\mu\text{F}$	4	7	15	ms	
T_{SHDN}	Thermal Shutdown Threshold	Enabled, $R_{load}=1\text{k}\Omega$		140		$^\circ\text{C}$	
T_{HYS}	Thermal Shutdown Hysteresis			25		$^\circ\text{C}$	
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOP-8L (Note 4)		110		$^\circ\text{C/W}$	
		MSOP-8L-EP (Note 5)		60		$^\circ\text{C/W}$	
		SOT25 (Note 6)		157		$^\circ\text{C/W}$	
		DFN2018-6 (Note 7)		70		$^\circ\text{C/W}$	

Notes:

4. Test condition for SOP-8L: Device mounted on FR-4, 2oz copper, with minimum recommended pad layout.
5. Test condition for MSOP-8L-EP: Device mounted on 2" x 2" FR-4 substrate PC board, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.
6. Test condition for SOT25: Device mounted on FR-4, 2oz copper, with minimum recommended pad layout.
7. Test condition for DFN2018-6: Device mounted on FR-4 2-layer board, 2oz copper, with minimum recommended pad on top layer and 3 vias to bottom layer 1.0"x1.4" ground plane.

Typical Performance Characteristics

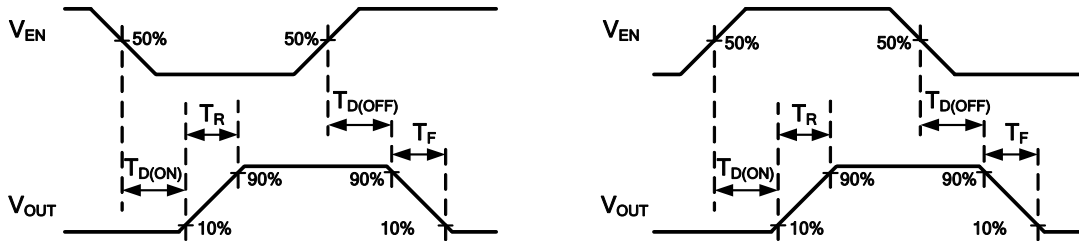
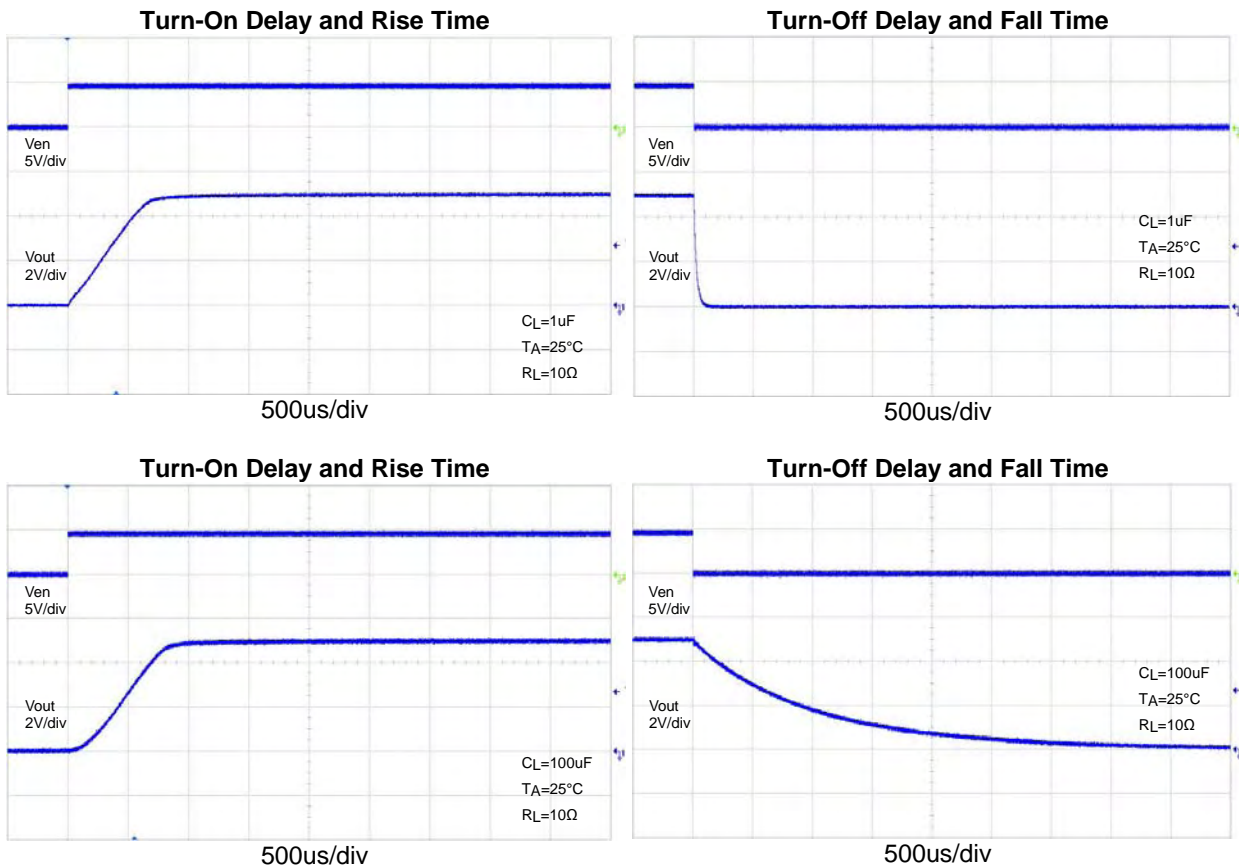


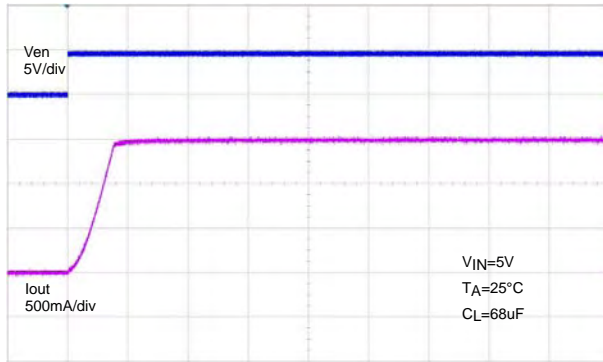
Figure 1. Voltage Waveforms: AP2161 (left), AP2171 (right)

All Enable Plots are for AP2171 Active High



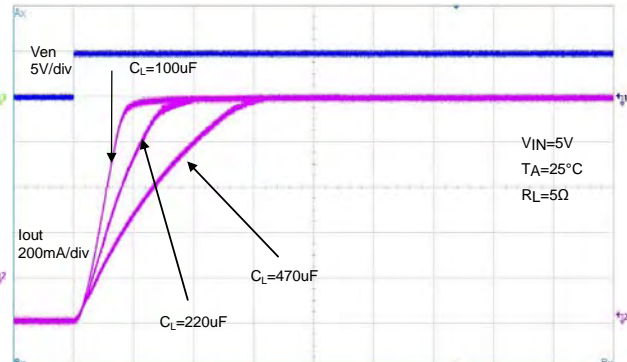
Typical Performance Characteristics (Continued)

Short Circuit Current, Device Enabled Into Short



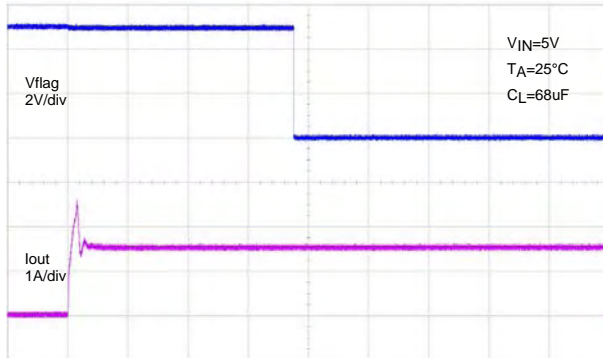
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Inrush Current



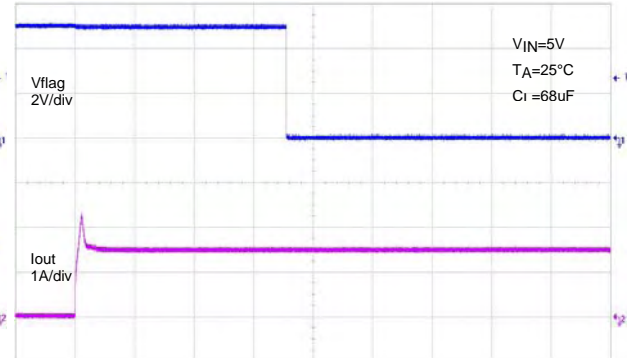
1ms/div

1 Ω Load Connected to Enabled Device



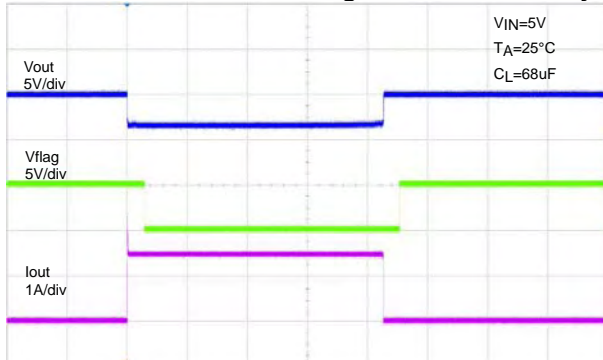
2ms/div

2Ω Load Connected to Enabled Device



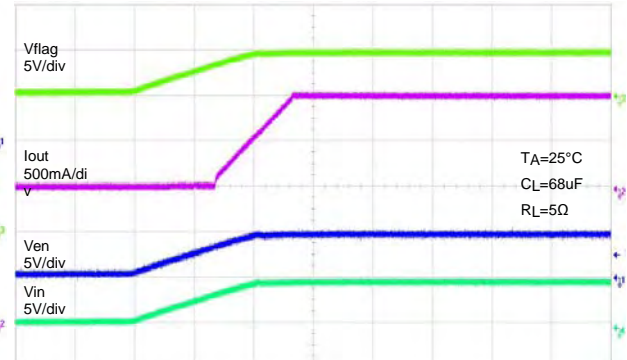
2ms/div

Short Circuit with Blanking Time and Recovery



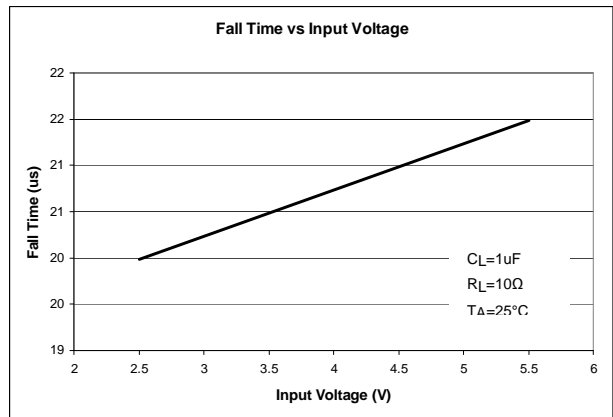
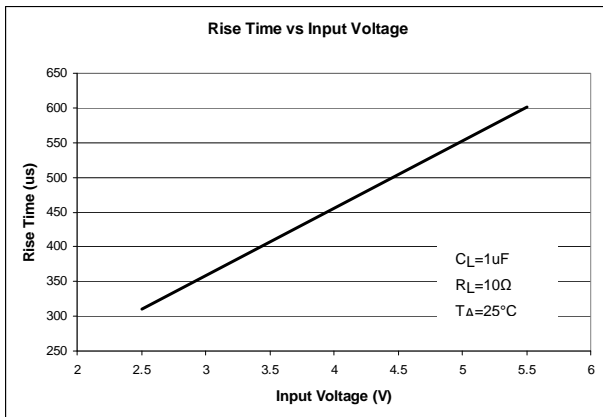
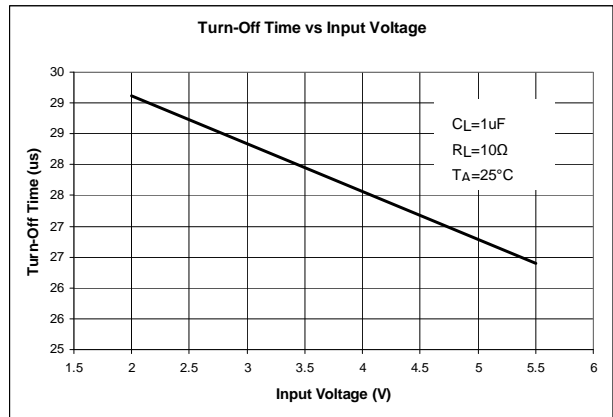
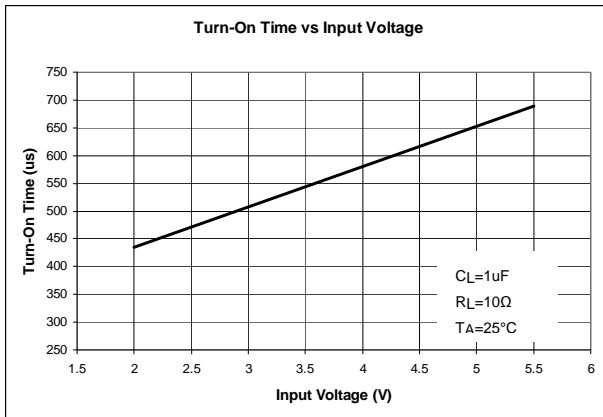
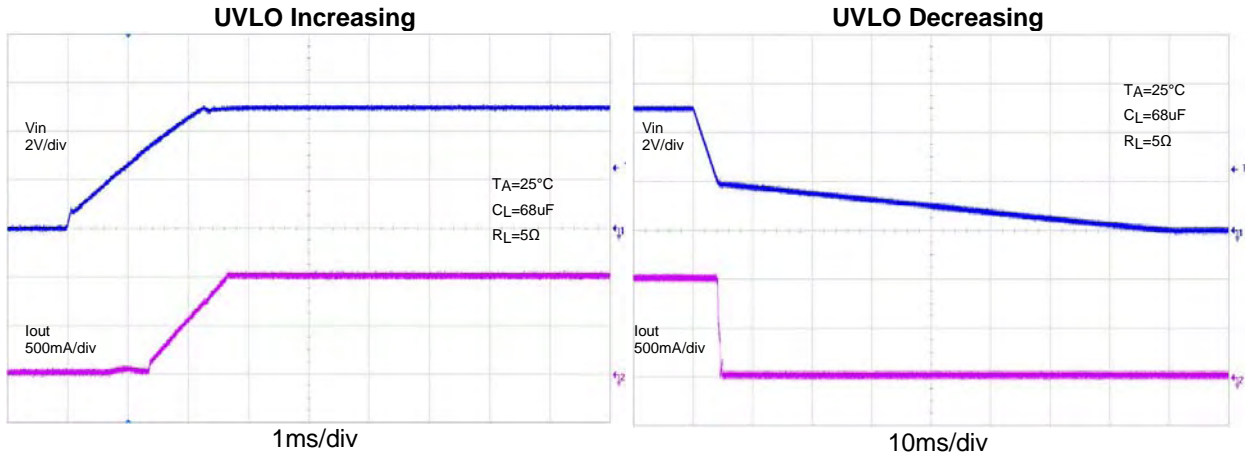
20ms/div

Power On

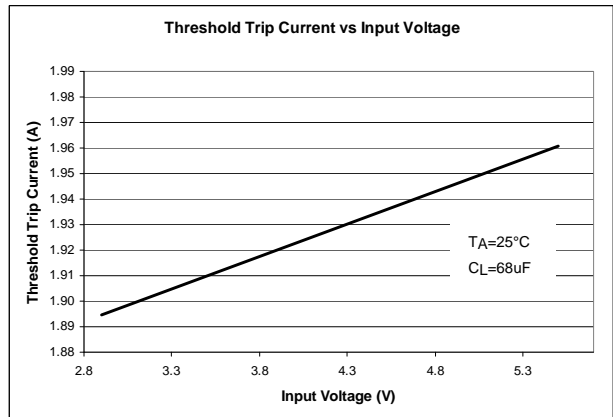
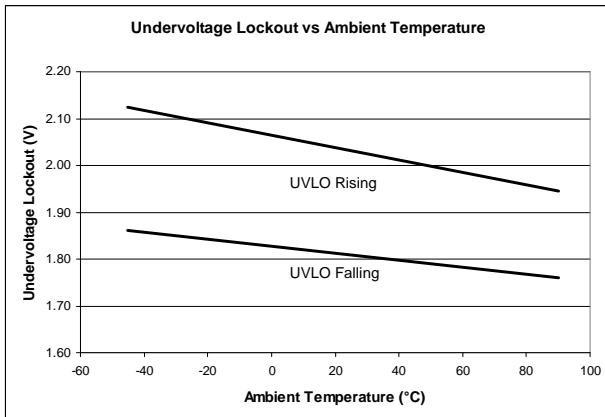
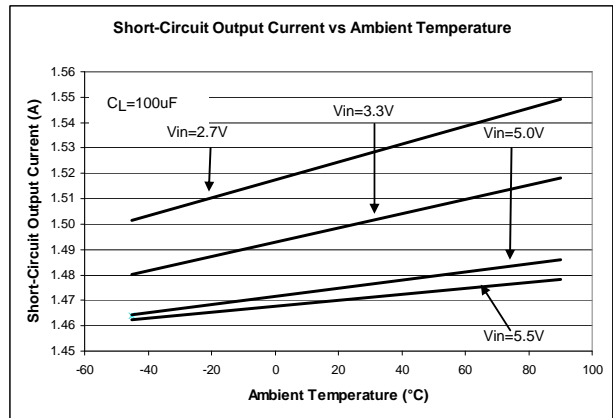
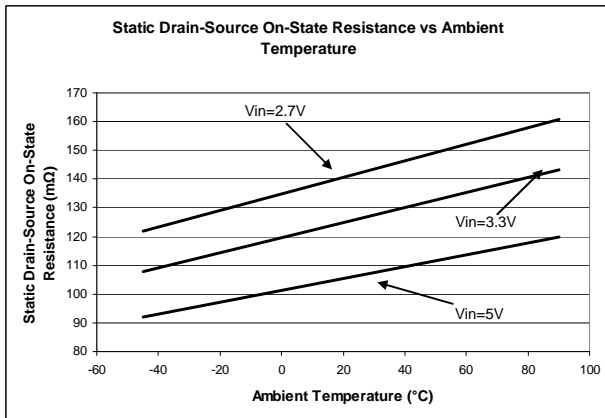
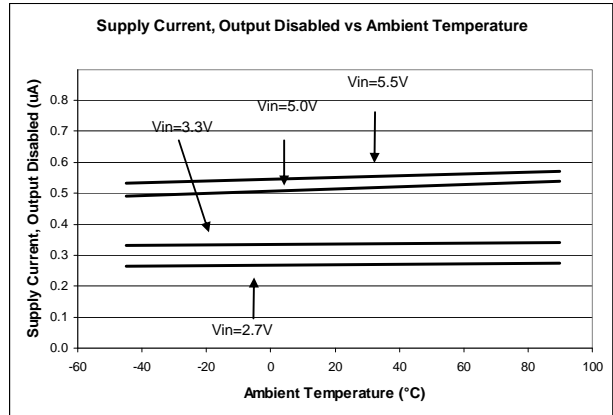
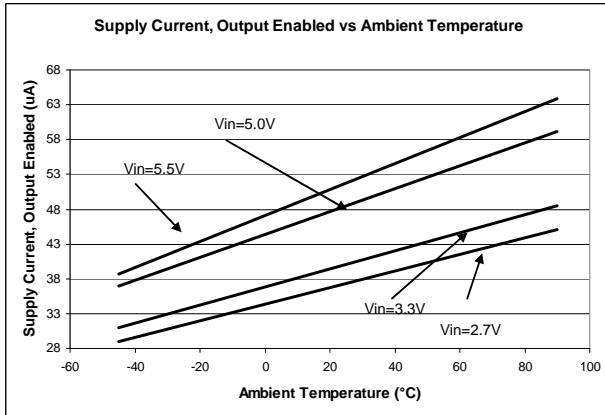


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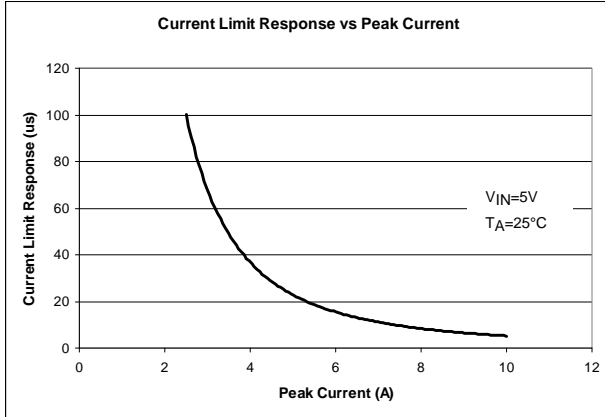
Typical Performance Characteristics (Continued)



Typical Performance Characteristics (Continued)



Typical Performance Characteristics (Continued)



Application Note

Power Supply Considerations

A 0.01- μ F to 0.1- μ F X7R or X5R ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the input (10- μ F minimum) and output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.01- μ F to 0.1- μ F ceramic capacitor improves the immunity of the device to short-circuit transients.

Over-current and Short Circuit Protection

An internal sensing FET is employed to check for over-current conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an over-current condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault stays long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted to GND before the device is enabled or before V_{IN} has been applied. The AP2161/AP2171 senses the short circuit and immediately clamps output current to a certain safe level namely I_{LIMIT} .

In the second condition, an output short or an overload occurs while the device is enabled. At the instance the overload occurs, higher current may flow for a very short period of time before the current limit function can react. After the current limit function has tripped (reached the over-current trip threshold), the device switches into current limiting mode and the current is clamped at I_{LIMIT} .

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold (I_{TRIG}) is reached or until the thermal limit of the device is exceeded. The AP2161/AP2171 is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its current limiting mode and is set at I_{LIMIT} .

Note that when the output has been shorted to GND at extremely low temperature ($< -30^{\circ}\text{C}$), a minimum 120- μ F electrolytic capacitor on the output pin is recommended. A correct capacitor type with capacitor voltage rating and temperature characteristics must be properly chosen so that capacitance value does not drop too low at the extremely low temperature operation. A recommended capacitor should have temperature characteristics of less than 10% variation of capacitance change when operated at extremely low temp. Our recommended aluminum electrolytic capacitor type is Panasonic FC series.

FLG Response

When an over-current or over-temperature shutdown condition is encountered, the FLG open-drain output goes active low after a nominal 7-ms deglitch timeout. The FLG output remains low until both over-current and over-temperature conditions are removed. Connecting a heavy capacitive load to the output of the device can cause a momentary over-current condition, which does not trigger the FLG due to the 7-ms deglitch timeout. The AP2161/AP2171 is designed to eliminate false over-current reporting without the need of external components to remove unwanted pulses.

Application Note (Continued)

Power Dissipation and Junction Temperature

The low on-resistance of the internal MOSFET allows the small surface-mount packages to pass large current. Using the maximum operating ambient temperature (T_A) and $R_{DS(ON)}$, the power dissipation can be calculated by:

$$P_D = R_{DS(ON)} \times I^2$$

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

- T_A = Ambient temperature °C
- $R_{\theta JA}$ = Thermal resistance
- P_D = Total power dissipation

Thermal Protection

Thermal protection prevents the IC from damage when heavy-overload or short-circuit faults are present for extended periods of time. The AP2161/AP2171 implements a thermal sensing to monitor the operating junction temperature of the power distribution switch. Once the die temperature rises to approximately 145°C due to excessive power dissipation in an over-current or short-circuit condition, the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit allowing the device to cool down approximately 25°C before the switch turns back on. The FLG open-drain output is asserted when an over-temperature shutdown or over-current occurs with 7-ms deglitch.

Under-voltage Lockout (UVLO)

Under-voltage lockout function (UVLO) keeps the internal power switch from being turned on until the power supply has reached at least 1.9V, even if the switch is enabled. Whenever the input voltage falls below approximately 1.9V, the power switch is quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed.

Host/Self-Powered And Bus-Powered HUBs

Hosts and self-powered hubs have a local power supply that powers the embedded functions and the downstream ports (see Figure 2). This power supply must provide from 5.25V to 4.75V to the board side of the downstream connection under full-load and no-load conditions. Hosts and SPHs are required to have current-limit protection and must report over-current conditions to the USB controller. Typical SPHs are desktop PCs, monitors, printers, and stand-alone hubs.

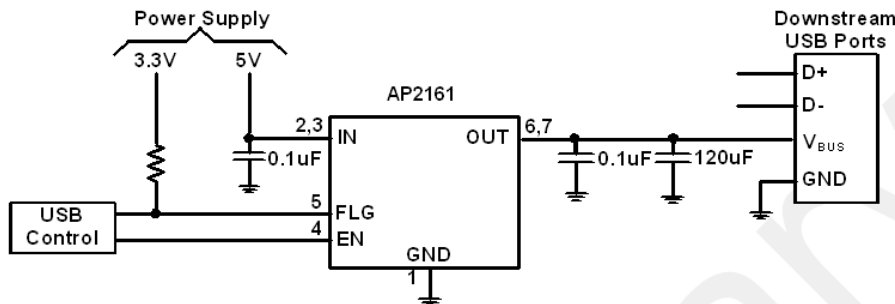


Figure 2. Typical One-Port USB Host / Self-Powered Hub

Application Note (Continued)

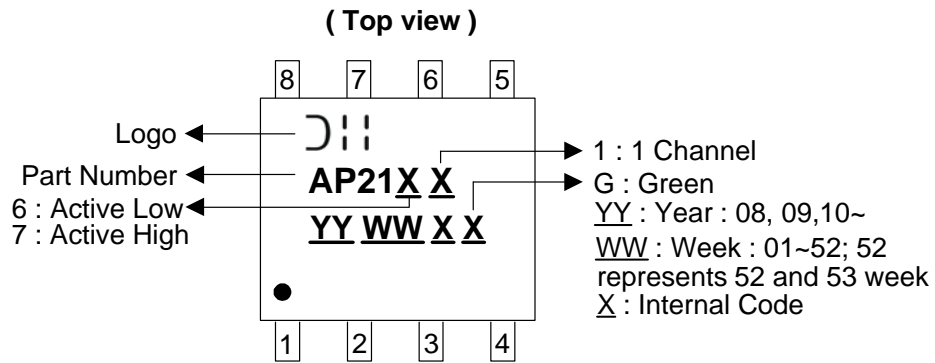
Generic Hot-Plug Applications

In many applications it may be necessary to remove modules or pc boards while the main unit is still operating. These are considered hot-plug applications. Such implementations require the control of current surges seen by the main power supply and the card being inserted. The most effective way to control these surges is to limit and slowly ramp the current and voltage being applied to the card, similar to the way in which a power supply normally turns on. Due to the controlled rise times and fall times of the AP2161/AP2171, these devices can be used to provide a softer start-up to devices being hot-plugged into a powered system. The UVLO feature of the AP2161/AP2171 also ensures that the switch is off after the card has been removed, and that the switch is off during the next insertion.

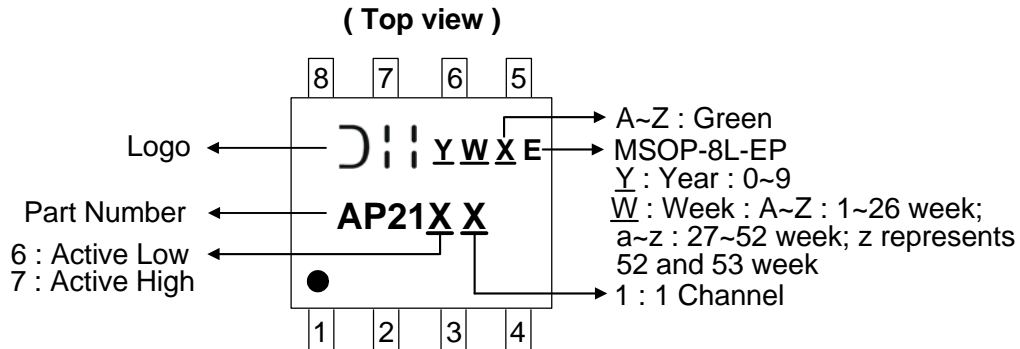
By placing the AP2161/AP2171 between the Vcc input and the rest of the circuitry, the input power reaches these devices first after insertion. The typical rise time of the switch is approximately 1ms, providing a slow voltage ramp at the output of the device. This implementation controls system surge current and provides a hot-plugging mechanism for any device.

Marking Information

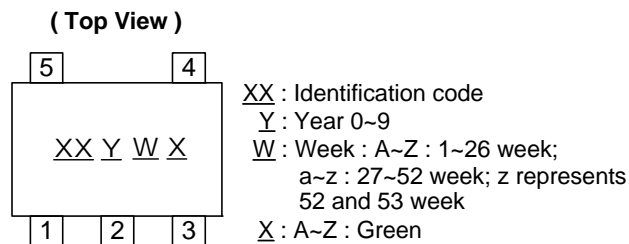
(1) SOP-8L



(2) MSOP-8L-EP



(3) SOT25

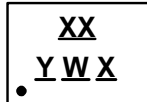


Device	Package type	Identification Code
AP2161W	SOT25	HT
AP2171W	SOT25	HU

Marking Information (Continued)

(4) DFN2018-6

(Top View)

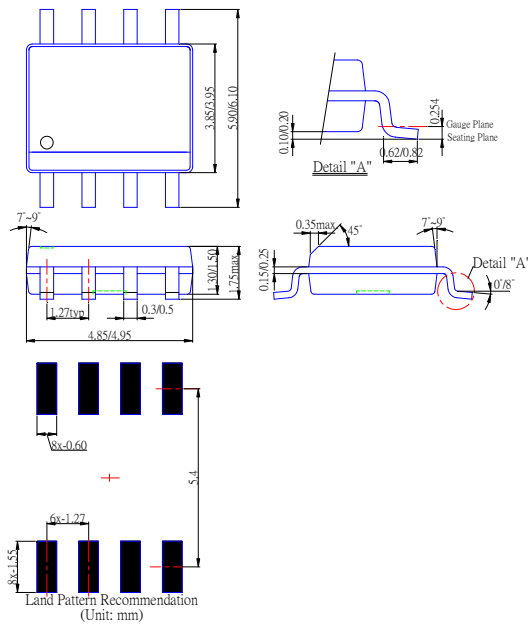


XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents
52 and 53 week
X : A~Z : Green

Device	Package type	Identification Code
AP2161FM	DFN2018-6	HT
AP2171FM	DFN2018-6	HU

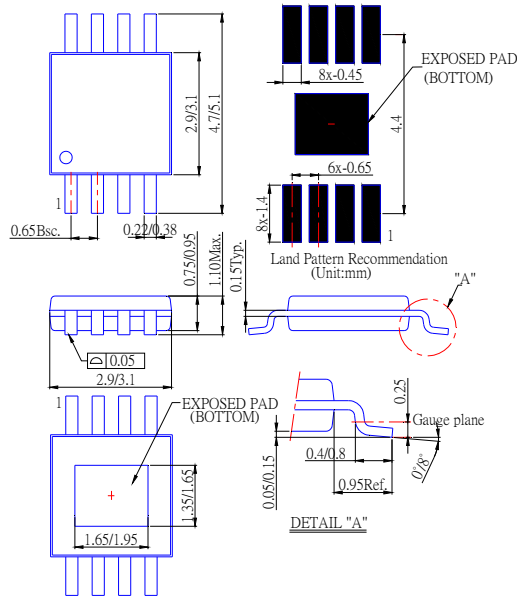
Package Information (All Dimensions in mm)

(1) Package Type: SOP-8L

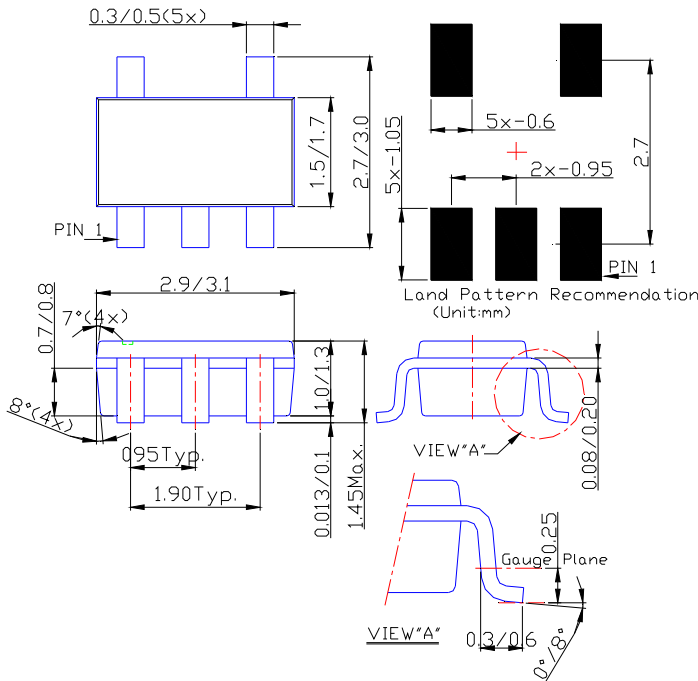


Package Information (Continued)

(2) Package Type: MSOP-8L-EP

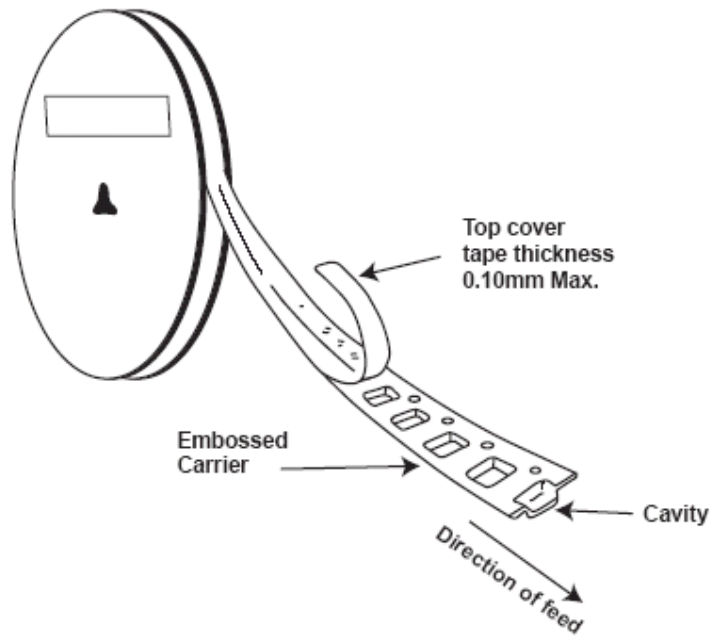
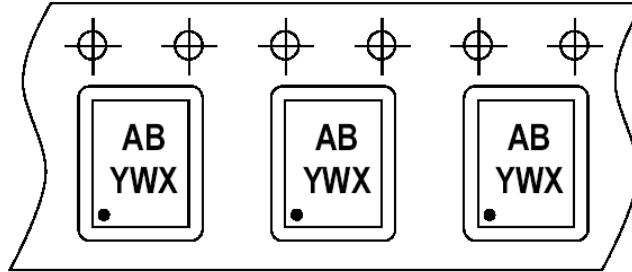


(3) Package Type: SOT25



Taping Orientation

For DFN2018-6



Notes: 8. The taping orientation of the other package type can be found on our website at <http://www.diodes.com/datasheets/ap02007.pdf>

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1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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